

Three-Wire Serial EEPROM 16-Kbit (2,048 x 8 or 1,024 x 16)

Features

- · Low-Voltage Operation:
 - V_{CC} = 1.8V to 5.5V
 - V_{CC} = 2.7V to 5.5V
- User-Selectable Internal Organized as 2,048 x 8 (16K) or 1,024 x 16 (16K)
- Industrial Temperature Range: -40°C to +85°C
- · Three-Wire Serial Interface
- · Sequential Read Operation
- · Schmitt Trigger, Filtered Inputs for Noise Suppression
- 2 MHz Clock Rate (5V)
- · Self-Timed Write Cycle within 10 ms Maximum
- · High Reliability:
 - Endurance: 1,000,000 write cycles
 - Data retention: 100 years
- Green Package Options (Lead-free/Halide-free/RoHS compliant)

Packages

• 8-Lead SOIC, 8-Lead TSSOP, 8-Pad UDFN and 8-Lead PDIP

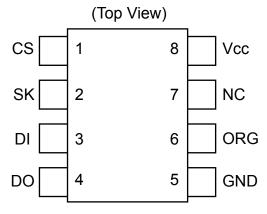
Table of Contents

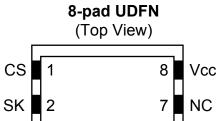
Fea	Features1						
Pa	ckages	S	1				
1.	Pack	age Types (not to scale)	4				
2.	Pin Descriptions						
	2.1.	Chip Select (CS)					
	2.2.	Serial Data Clock (SK)					
	2.3.	Serial Data Input (DI)					
	2.4.	Serial Data Output (DO)					
	2.5.	Ground (GND)					
	2.6.	Internal Organization (ORG)					
	2.7.	Device Power Supply (V _{CC})					
3.	Desc	ription	7				
	3.1.	Block Diagram	7				
4.	Elect	rical Characteristics	8				
	4.1.	Absolute Maximum Ratings	8				
	4.2.	DC and AC Operating Range	8				
	4.3.	DC Characteristics	8				
	4.4.	AC Characteristics	g				
	4.5.	Synchronous Data Timing	10				
	4.6.	Electrical Specifications	11				
5.	Devi	ce Commands and Addressing	12				
	5.1.	READ	12				
	5.2.	Erase/Write Enable (EWEN)	13				
	5.3.	Erase/Write Disable (EWDS)	13				
	5.4.	ERASE	14				
	5.5.	WRITE	14				
	5.6.	Write All (WRAL)	15				
	5.7.	Erase All (ERAL)	15				
6.	Pack	aging Information	17				
	6.1.	Package Marking Information	17				
7.	Revis	sion History	28				
The	e Micro	ochip Website	29				
Pro	duct C	Change Notification Service	29				
		r Support					
		dentification Systemdentification System					
		Devices Code Protection Feature					
	inp						

Legal Notice	31
Trademarks	31
Quality Management System	32
Worldwide Sales and Service	33

1. Package Types (not to scale)

8-lead PDIP/SOIC/TSSOP





6 ORG

GND

5

DI

DO

3

2. Pin Descriptions

The descriptions of the pins are listed in Table 2-1.

Table 2-1. Pin Function Table

Name	8-Lead PDIP	8-Lead SOIC	8-Lead TSSOP	8-Pad UDFN ⁽¹⁾	Function
CS	1	1	1	1	Chip Select
SK	2	2	2	2	Serial Data Clock
DI	3	3	3	3	Serial Data Input
DO	4	4	4	4	Serial Data Output
GND	5	5	5	5	Ground
ORG	6	6	6	6	Internal Organization
NC	7	7	7	7	No Connect
VCC	8	8	8	8	Device Power Supply

Note:

1. The exposed pad on this package can be connected to GND or left floating.

2.1 Chip Select (CS)

The Chip Select (CS) pin is used to control device selection. The AT93C86A is selected when the CS pin is high. When the device is not selected, data will not be accepted via the Serial Data Input (DI) pin, and the Serial Output (DO) pin will remain in a high-impedance state.

2.2 Serial Data Clock (SK)

The Serial Data Clock (SK) pin is used to synchronize the communication between a master and the AT93C86A. Instructions, addresses or data present on the Serial Data Input (DI) pin is latched in on the rising edge of SK, while output on the Serial Data Output (DO) pin is also clocked out on the rising edge of SK.

2.3 Serial Data Input (DI)

The Serial Data Input (DI) pin is used to transfer data into the device. It receives instructions, addresses and data. Data is latched on the rising edge of the Serial Data Clock (SK).

2.4 Serial Data Output (DO)

The Serial Data Output (DO) pin is used to transfer data out of the AT93C86A. During a read sequence, data is shifted out on this pin after the rising edge of the Serial Data Clock (SK).

This pin also outputs the Ready/Busy status of the part if CS is brought high after being low for a minimum of tcs and an erase or write operation has been initiated.

2.5 **Ground (GND)**

The ground reference for the power supply. The Ground (GND) pin should be connected to the system ground.

DS20006261A-page 5 © 2019 Microchip Technology Inc.

2.6 Internal Organization (ORG)

The Internal Organization (ORG) pin is used to select between the x16 or x8 memory organizations of the device. When the ORG pin is tied to V_{CC} , the x16 memory organization is selected. When the ORG pin is tied to V_{SS} , the x8 memory organization is selected.

If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 $M\Omega$ pull-up resistor, then the x16 organization is selected.

2.7 Device Power Supply (V_{CC})

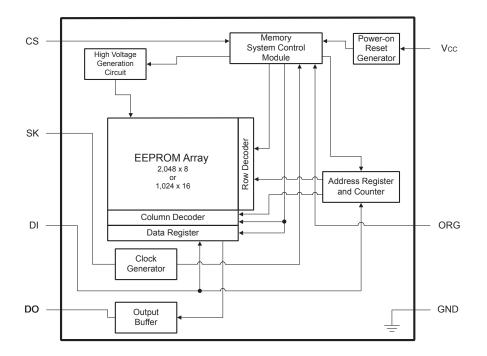
The Device Power Supply (V_{CC}) pin is used to supply the source voltage to the device. Operations at invalid V_{CC} voltages may produce spurious results and should not be attempted.

3. Description

The AT93C86A provides 16,384 bits of Serial Electrically Erasable and Programmable Read-Only Memory (EEPROM) organized as 1,024 words of 16 bits each (when the ORG pin is connected to V_{CC}) and 2,048 words of 8 bits each (when the ORG pin is tied to ground). The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operations are essential. The AT93C86A is available in space-saving 8-lead SOIC, 8-lead TSSOP, 8-pad UDFN and 8-lead PDIP packages. All packages operate from 1.8V to 5.5V or from 2.7V to 5.5V.

The AT93C86A is enabled through the Chip Select (CS) pin and accessed via a three-wire serial interface consisting of Data Input (DI), Data Output (DO), and Serial Data Clock (SK). Upon receiving a READ instruction at DI, the address is decoded, and the data is clocked out serially on the DO pin. The write cycle is completely self-timed, and no separate erase cycle is required before write. The write cycle is only enabled when the part is in the Erase/Write Enable state. When CS is brought high following the initiation of a write cycle, the DO pin outputs the Ready/Busy status of the part.

3.1 Block Diagram



Note:

1. When the ORG pin is connected to V_{CC} , the x16 organization is selected. When it is connected to ground, the x8 organization is selected. If the ORG pin is left unconnected, and the application does not load the input beyond the capability of the 10 M Ω pull-up resistor, then the x16 organization is selected.

4. Electrical Characteristics

4.1 Absolute Maximum Ratings

Temperature under bias -55°C to +125°C

Storage temperature -65°C to +150°C

V_{CC} 6.25V

Voltage on any pin with respect to ground -1.0V to +7.0V

DC output current 5.0 mA
ESD protection 2 kV

Note: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

4.2 DC and AC Operating Range

Table 4-1. DC and AC Operating Range

AT93C86A		
Operating Temperature (Case)	Industrial Temperature Range	-40°C to +85°C
V _{CC} Power Supply	Low-Voltage Grade	1.8V to 5.5V

4.3 DC Characteristics

Table 4-2. DC Characteristics(1)

Parameter	Symbol	Minimum	Typical	Maximum	Units	Test Conditions
Supply Voltage	V _{CC1}	1.8	_	5.5	V	
Supply Voltage	V _{CC2}	2.7	_	5.5	V	
Supply Voltage	V _{CC3}	4.5	_	5.5	V	
Supply Current	I _{CC1}	_	0.5	2.0	mA	V _{CC} = 5.0V, Read at 1 MHz
Supply Current	I _{CC2}	_	0.5	2.0	mA	V _{CC} = 5.0V, Write at 1 MHz
Standby Current (1.8V Option)	I _{SB1}	_	0.4	1.0	μA	V _{CC} = 1.8V, CS = 0V
Standby Current (2.7V Option)	I _{SB2}	_	6.0	10.0	μA	V _{CC} = 2.7V, CS = 0V
Standby Current (5.0V Option)	I _{SB3}	_	10.0	15.0	μA	V _{CC} = 5.0V, CS = 0V
Input Leakage Current	I _{IL}	_	0.1	3.0	μA	V _{IN} = 0 to V _{CC}
Output Leakage Current	I _{LO}	_	0.1	3.0	μA	V _{IN} = 0 to V _{CC}

continued	continued									
Parameter	Symbol	Minimum	Typical	Maximum	Units	Test Conditions				
Input Low-Voltage	V_{IL1}	-0.6	_	0.8	V	2.7V ≤ V _{CC} ≤ 5.5V (Note 2)				
Input High-Voltage	V _{IH1}	2.0	_	V _{CC} + 1	V	2.7V ≤ V _{CC} ≤ 5.5V (Note 2)				
Input Low-Voltage	V_{IL2}	-0.6	_	V _{CC} x 0.3	V	1.8V ≤ V _{CC} ≤ 2.7V (Note 2)				
Input High-Voltage	V _{IH2}	V _{CC} x 0.7	_	V _{CC} + 1	V	1.8V ≤ V _{CC} ≤ 2.7V (Note 2)				
Output Low-Voltage	V _{OL1}	_	_	0.4	V	$2.7V \le V_{CC} \le 5.5V$, $I_{OL} = 2.1 \text{ mA}$				
Output High-Voltage	V _{OH1}	2.4	_	_	V	$2.7V \le V_{CC} \le 5.5V$, $I_{OH} = -0.4 \text{ mA}$				
Output Low-Voltage	V _{OL2}	_	_	0.2	V	$1.8V \le V_{CC} \le 2.7V$, $I_{OL} = 0.15 \text{ mA}$				
Output High-Voltage	V _{OH2}	V _{CC} - 0.2	_	_	V	$1.8V \le V_{CC} \le 2.7V$, $I_{OH} = -100 \ \mu A$				

Note:

- 1. Applicable over recommended operating range from: $T_A = -40^{\circ}\text{C}$ to +85°C, $V_{CC} = 1.8\text{V}$ to 5.5V (unless otherwise noted).
- 2. V_{IL} min and V_{IH} max are reference only and are not tested.

4.4 AC Characteristics

Table 4-3. AC Characteristics(1)

Parameter	Symbol	Minimum	Typical	Maximum	Units	Test Conditions
Clock Frequency, SK	f _{SK}	0	_	2	MHz	4.5V ≤ V _{CC} ≤ 5.5V
		0	_	1	MHz	2.7V ≤ V _{CC} ≤ 5.5V
		0	_	250	kHz	$1.8V \le V_{CC} \le 5.5V$
High Time, SK	t _{skH}	250	_	_	ns	2.7V ≤ V _{CC} ≤ 5.5V
		1000	_	_	ns	1.8V ≤ V _{CC} ≤ 5.5V
Low Time, SK	t _{SKL}	250	_	_	ns	2.7V ≤ V _{CC} ≤ 5.5V
		1000	_	_	ns	1.8V ≤ V _{CC} ≤ 5.5V
Minimum CS Low Time	t _{CS}	250	_	_	ns	2.7V ≤ V _{CC} ≤ 5.5V
		1000	_	_	ns	1.8V ≤ V _{CC} ≤ 5.5V
CS Setup Time	t _{CSS}	50	_	_	ns	2.7V ≤ V _{CC} ≤ 5.5V, Relative to SK
		200	_	_	ns	1.8V ≤ V _{CC} ≤ 5.5V, Relative to SK
DI Setup Time	t _{DIS}	100	_	_	ns	2.7V ≤ V _{CC} ≤ 5.5V, Relative to SK
		400	_	_	ns	1.8V ≤ V _{CC} ≤ 5.5V, Relative to SK
CS Hold Time	t _{CSH}	0	_	_	ns	Relative to SK

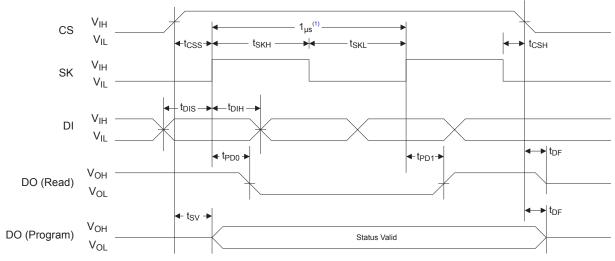
continued								
Parameter	Symbol	Minimum	Typical	Maximum	Units	Test Conditions		
DI Hold Time	t _{DIH}	100	_	_	ns	2.7V ≤ V _{CC} ≤ 5.5V, Relative to SK		
		400	_	_	ns	1.8V ≤ V _{CC} ≤ 5.5V, Relative to SK		
Output Delay to 1	t _{PD1}	_	_	250	ns	2.7V ≤ V _{CC} ≤ 5.5V		
		_	_	1000	ns	1.8V ≤ V _{CC} ≤ 5.5V		
Output Delay to 0	t _{PD0}	_	_	250	ns	2.7V ≤ V _{CC} ≤ 5.5V		
		_	_	1000	ns	1.8V ≤ V _{CC} ≤ 5.5V		
CS to Status Valid	t _{SV}	_	_	250	ns	2.7V ≤ V _{CC} ≤ 5.5V		
		_	_	1000	ns	1.8V ≤ V _{CC} ≤ 5.5V		
CS to DO in High-impedance	t _{DF}		_	150	ns	$2.7V \le V_{CC} \le 5.5V$, $CS = V_{IL}$		
		_	_	400	ns	$1.8V \le V_{CC} \le 5.5V,$ $CS = V_{IL}$		
Write Cycle Time	t _{WP}	0.1	3	10	ms	1.8V ≤ V _{CC} ≤ 5.5V		

Note:

1. Applicable over recommended operating range from $T_A = -40^{\circ}\text{C}$ to +85°C, $V_{CC} = \text{As Specified}$, $C_L = 1$ TTL Gate and 100 pF (unless otherwise noted).

4.5 Synchronous Data Timing

Figure 4-1. Synchronous Data Timing



Note:

1. This is the minimum SK period.

4.6 Electrical Specifications

4.6.1 Power-Up Requirements and Reset Behavior

During a power-up sequence, the V_{CC} supplied to the AT93C86A should monotonically rise from GND to the minimum V_{CC} level, as specified in Table 4-1, with a slew rate no faster than 0.1 V/ μ s.

4.6.1.1 Device Reset

To prevent inadvertent write operations or any other spurious events from occurring during a power-up sequence, the AT93C86A includes a Power-on Reset (POR) circuit. Upon power-up, the device will not respond to any commands until the V_{CC} level crosses the internal voltage threshold (V_{POR}) that brings the device out of Reset and into Standby mode.

The system designer must ensure the instructions are not sent to the device until the V_{CC} supply has reached a stable value greater than or equal to the minimum V_{CC} level. Additionally, once the V_{CC} is greater than or equal to the minimum V_{CC} level, the bus master must wait at least t_{PUP} before sending the first command to the device. See Power-up Conditions⁽¹⁾ for the values associated with these power-up parameters.

Table 4-4. Power-up Conditions(1)

Symbol	Parameter	Min.	Max.	Units
t _{PUP}	Time required after V _{CC} is stable before the device can accept commands	100	_	μs
V _{POR}	Power-on Reset Threshold Voltage	_	1.5	V
t _{POFF}	Minimum time at V _{CC} = 0V between power cycles	500	_	ms

Note:

1. These parameters are characterized but they are not 100% tested in production.

If an event occurs in the system where the V_{CC} level supplied to the AT93C86A drops below the maximum V_{POR} level specified, it is recommended that a full power cycle sequence be performed by first driving the V_{CC} pin to GND, waiting at least the minimum t_{POFF} time and then performing a new power-up sequence in compliance with the requirements defined in this section.

4.6.2 Pin Capacitance

Table 4-5. Pin Capacitance(1)

Symbol	Test Condition	Max.	Units	Conditions
C _{OUT}	Output Capacitance (DO)	5	pF	V _{OUT} = 0V
C _{IN}	Input Capacitance (CS, SK, DI, ORG)	5	pF	V _{IN} = 0V

Note:

1. This parameter is characterized but is not 100% tested in production.

4.6.3 EEPROM Cell Performance Characteristics

Table 4-6. EEPROM Cell Performance Characteristics

Operation	Test Condition	Min.	Max.	Units
Write Endurance ⁽¹⁾	$T_A = 25^{\circ}C, V_{CC} = 5.0V$	1,000,000	_	Write Cycles
Data Retention ⁽¹⁾	T _A = 55°C	100	_	Years

Note:

1. Performance is determined through characterization and the qualification process.

5. Device Commands and Addressing

The AT93C86A is accessed via a simple and versatile three-wire serial communication interface. Device operation is controlled by seven instructions issued by the Host processor. A valid instruction starts with a rising edge of CS and consists of a Start bit (SB), followed by the appropriate opcode, and the desired memory address location.

Table 5-1. AT93C86A Instruction Set

Instruction	SB	Opcode	Add	ress	Data		Comments
			X8(1)	X16 ⁽¹⁾	X8	X16	
READ	1	10	A ₁₀ -A ₀	A9-A0			Reads data stored in memory at specified address.
EWEN	1	00	11XXXXXXXXX	11XXXXXXXX			Write Enable must precede all programming modes.
ERASE	1	11	A ₁₀ -A ₀	A9-A0			Erases memory location A _N -A ₀ .
WRITE	1	01	A ₁₀ -A ₀	A9-A0	D7-D0	D ₁₅ -D ₀	Writes memory location A _N -A ₀ .
ERAL	1	00	10XXXXXXXX	10XXXXXXXX			Erases all memory locations. Valid only at V _{CC3} . See Table 4-2.
WRAL	1	00	01XXXXXXXXX	01XXXXXXXX	D ₇ -D ₀	D ₁₅ -D ₀	Writes all memory locations. Valid only at V _{CC3} . See Table 4-2
EWDS	1	00	00XXXXXXXX	00XXXXXXXX			Disables all programming instructions.

Note:

1. The 'x' in the address field represents a "don't care" bit and must be sent to the device.

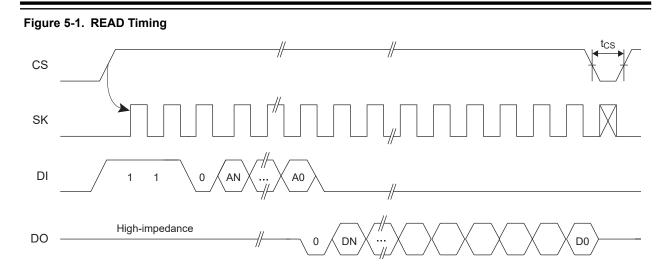
Table 5-2. Organization Key for Timing Diagrams

I/O	AT93C86A (16K)			
	x8	x16		
A _N	A ₁₀	A ₉		
D _N	D ₇	D ₁₅		

5.1 READ

The READ instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the DO pin. Output data changes are synchronized with the rising edges of the SK pin. The AT93C86A supports sequential read operations. The device will automatically increment the internal Address Pointer and clock out the next memory location as long as Chip Select (CS) is held high. In this case, the dummy bit (Logic '0') will not be clocked out between memory locations, thus allowing for a continuous stream of data to be read.

Note: A dummy bit (logic '0') precedes the initial 8-bit or 16-bit data output string.

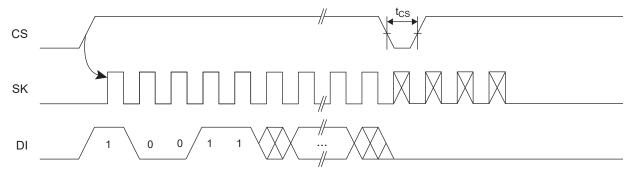


5.2 Erase/Write Enable (EWEN)

To ensure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out.

Note: Once in the write enabled state, programming remains enabled until an EWDS instruction is executed, or V_{CC} power is removed from the part.

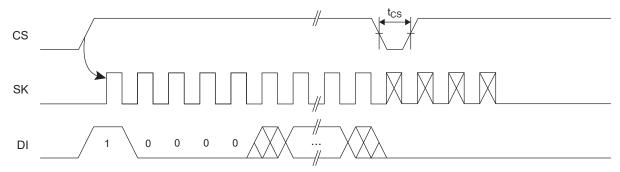
Figure 5-2. EWEN Timing



5.3 Erase/Write Disable (EWDS)

To protect against accidental data disturbance, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the READ instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

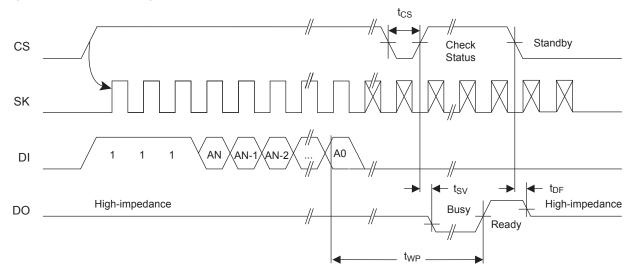




5.4 ERASE

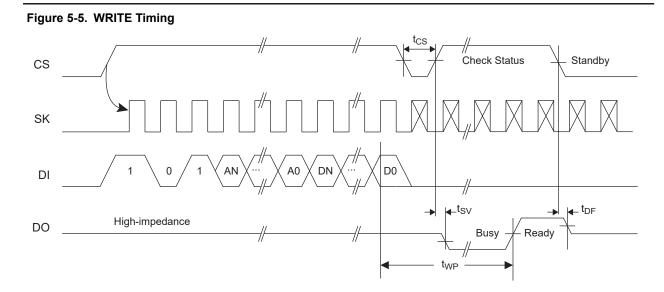
The ERASE instruction programs all bits in the specified memory location to the logic '1' state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} . A logic '1' at the DO pin indicates that the selected memory location has been erased, and the part is ready for another instruction.

Figure 5-4. ERASE Timing



5.5 WRITE

The WRITE instruction contains the 8 bits or 16 bits of data to be written into the specified memory location. The self-timed programming cycle, t_{WP} , starts after the last bit of data is received at DI pin . The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} . A logic '0' at DO indicates that programming is still in progress. A logic '1' indicates that the memory location at the specified address has been written with the data pattern contained in the instruction, and the part is ready for further instructions. A Ready/Busy status cannot be obtained if CS is brought high after the end of the self-timed programming cycle, t_{WP} .

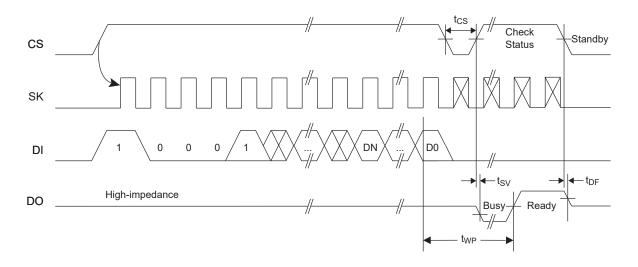


5.6 Write All (WRAL)

The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} .

Note: The WRAL instruction is valid only at V_{CC3} (see Table 4-2).

Figure 5-6. WRAL Timing

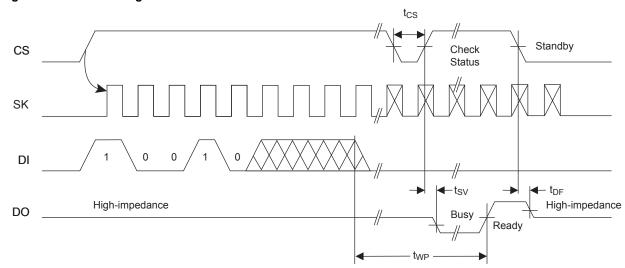


5.7 Erase All (ERAL)

The Erase All (ERAL) instruction programs every bit in the memory array to the logic '1' state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} .

Note: The ERAL instruction is valid only at V_{CC3} (see Table 4-2).

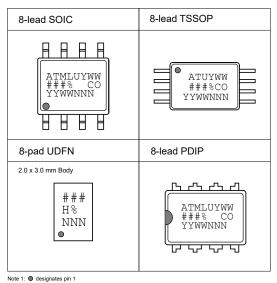
Figure 5-7. ERAL Timing



6. Packaging Information

6.1 Package Marking Information

AT93C86A: Package Marking Information

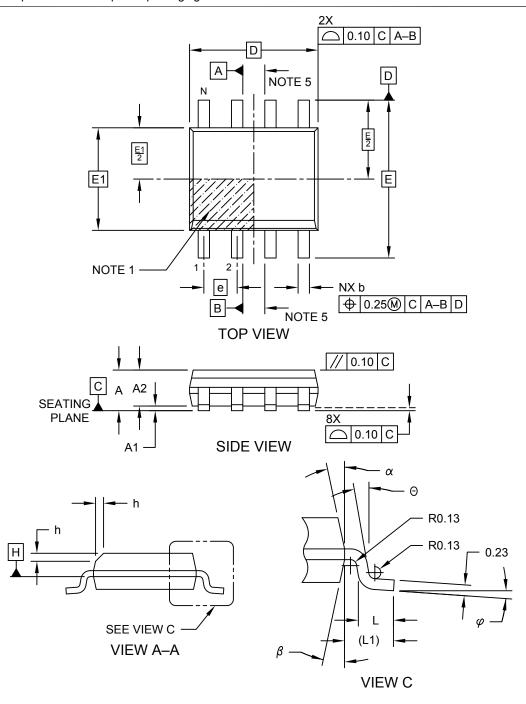


Note 2: Package drawings are not to scale

_	mber Trunca	ition			
AT93C86A			Trunc	cation Code ###: 86A	
Date Codes	3				Voltages
YY = Year		Y = Year		WW = Work Week of Assembly	% = Minimum Voltage
16: 2016	20: 2020	6: 2016	0: 2020	02: Week 2	L: 1.8V min
17: 2017	21: 2021	7: 2017	1: 2021	04: Week 4	Blank: 2.7V min
18: 2018	22: 2022	8: 2018	2: 2022		
19: 2019	23: 2023	9: 2019	3: 2023	52: Week 52	
Country of	Origin		Device	Grade	Atmel Truncation
CO = Count	ry of Origin		H or U:	Industrial Grade	AT: Atmel
	,				ATM: Atmel
					ATML: Atmel
Lot Numbe	r or Trace Co	ode	•		•
	anumeric Tra	0 1			

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 ln.) Body [SOIC]

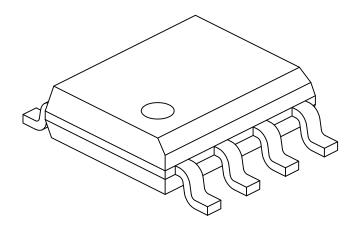
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing No. C04-057-SN Rev E Sheet 1 of 2 $\,$

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 ln.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		1.27 BSC	
Overall Height	Α	1	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff §	A1	0.10	-	0.25
Overall Width	Е	6.00 BSC		
Molded Package Width	E1	3.90 BSC		
Overall Length	D	4.90 BSC		
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40 - 1.27		1.27
Footprint	L1	1.04 REF		
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.17 - 0.25		0.25
Lead Width	b	0.31 - 0.51		
Mold Draft Angle Top	α	5° - 15°		
Mold Draft Angle Bottom	β	5°	-	15°

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

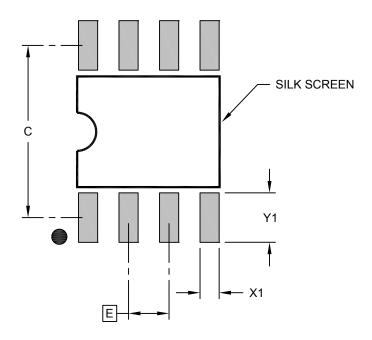
REF: Reference Dimension, usually without tolerance, for information purposes only.

5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-057-SN Rev E Sheet 2 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	С		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

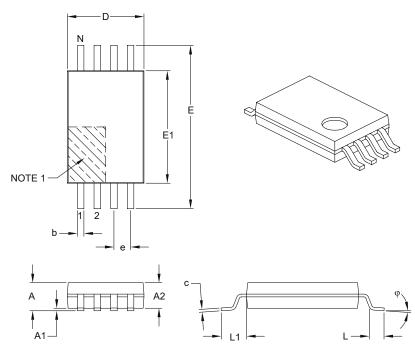
Notes:

Dimensioning and tolerancing per ASME Y14.5M
 BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev E

8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETERS		
	Dimension Limits	MIN	NOM	MAX	
Number of Pins	N		8		
Pitch	е		0.65 BSC		
Overall Height	A	_	-	1.20	
Molded Package Thickness	A2	0.80	1.00	1.05	
Standoff	A1	0.05	-	0.15	
Overall Width	E	6.40 BSC			
Molded Package Width	E1	4.30	4.40	4.50	
Molded Package Length	D	2.90	3.00	3.10	
Foot Length	L	0.45	0.60	0.75	
Footprint	L1	1.00 REF			
Foot Angle	φ	0° – 8°		8°	
Lead Thickness	С	0.09 – 0.20			
Lead Width	b	0.19	_	0.30	

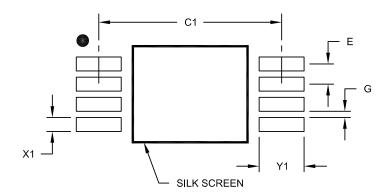
Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M.
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086B

8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	N	/ ILLIMETER	S	
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	C1		5.90	
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.45
Distance Between Pads	G	0.20		

Notes:

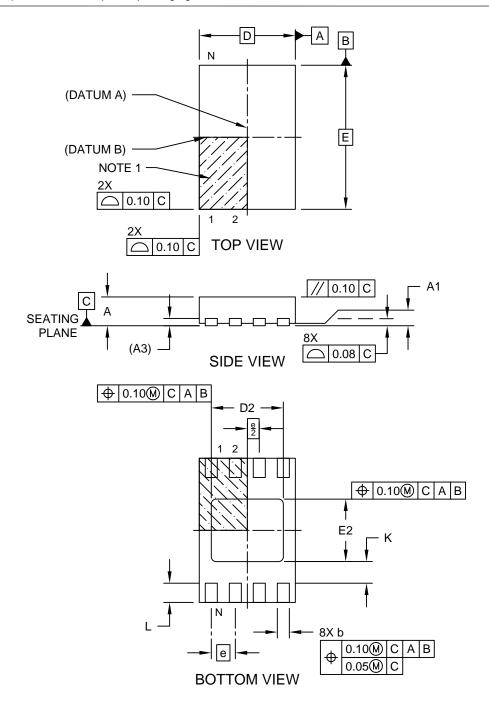
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2086A

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN] Atmel Legacy YNZ Package

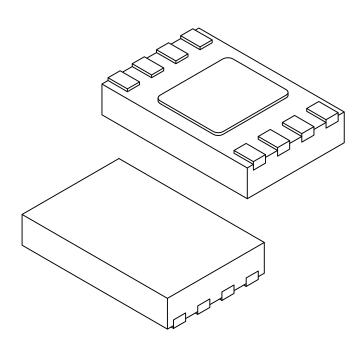
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-21355-Q4B Rev A Sheet 1 of 2

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN] Atmel Legacy YNZ Package

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			S
Dimension	Limits	MIN	NOM	MAX
Number of Terminals	N		8	
Pitch	е		0.50 BSC	
Overall Height	Α	0.50	0.55	0.60
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3	0.152 REF		
Overall Length	D	2.00 BSC		
Exposed Pad Length	D2	1.40 1.50 1.60		
Overall Width	Е		3.00 BSC	
Exposed Pad Width	E2	1.20	1.30	1.40
Terminal Width	b	0.18 0.25 0.30		0.30
Terminal Length	L	0.35	0.40	0.45
Terminal-to-Exposed-Pad	K	0.20	-	-

Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Package is saw singulated
- 3. Dimensioning and tolerancing per ASME Y14.5M

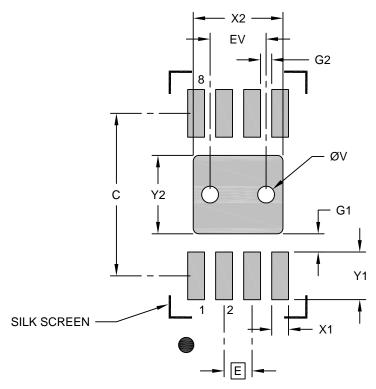
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-21355-Q4B Rev A Sheet 2 of 2

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN] Atmel Legacy YNZ Package

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	Е		0.50 BSC	
Optional Center Pad Width	X2			1.60
Optional Center Pad Length	Y2			1.40
Contact Pad Spacing	С		2.90	
Contact Pad Width (X8)	X1			0.30
Contact Pad Length (X8)	Y1			0.85
Contact Pad to Center Pad (X8)	G1	0.20		
Contact Pad to Contact Pad (X6)	G2	0.33		
Thermal Via Diameter	V		0.30	
Thermal Via Pitch	EV		1.00	

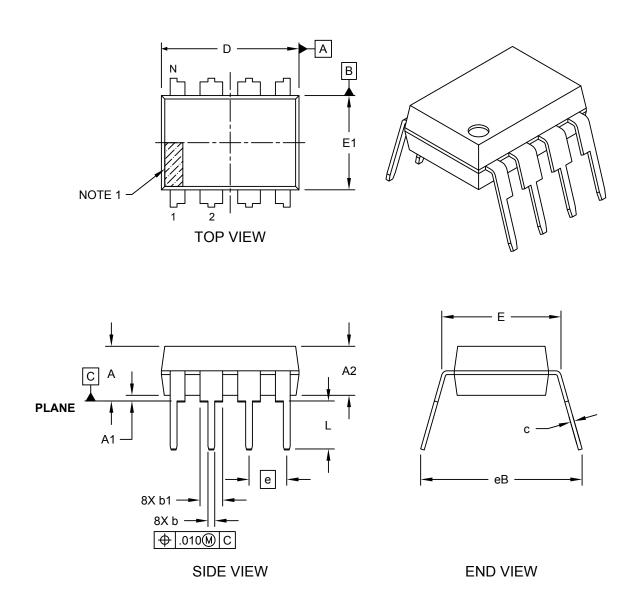
Notes:

- 1. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-21355-Q4B Rev A

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

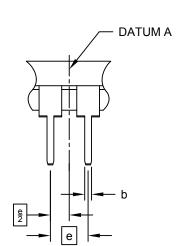
Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

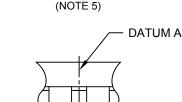


Microchip Technology Drawing No. C04-018-P Rev E Sheet 1 of 2

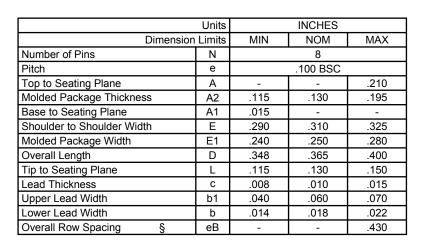
8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





ALTERNATE LEAD DESIGN



Notes:

- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 5. Lead design above seating plane may vary, based on assembly vendor.

Microchip Technology Drawing No. C04-018-P Rev E Sheet 2 of 2

7. Revision History

Revision A (October 2019)

Updated to the Microchip template. Microchip DS20006261 replaces Atmel documents 3408. Updated Package Marking Information. Removed lead finish designation. Updated trace code format in package markings. Updated section content throughout for clarification. Updated the PDIP, SOIC, TSSOP and UDFN package drawings to Microchip format.

Atmel AT93C86A 3408 Revision L (January 2017)

Added Bulk (Tube) Shipping Carrier Option. Changed Standard Quantity Tape and Reel Option to "T". Updated Ordering Information Table. Removed AT93C86A-W1.8-11 Part Number

Atmel AT93C86A 3408 Revision K (December 2015)

Correct Ordering Code Detail and update the 8S1 and 8MA2 package drawings

Atmel AT93C86A 3408 Revision J (January 2015)

Add the UDFN extended quantity option and update the ordering information section. Update the 8MA2 and 8P3 package drawings.

Atmel AT93C86A 3408 Revision I (August 2014)

Update pinouts, 8MA2 package drawings, grammatical changes, document template, logos, and disclaimer page. No changes to functional specification.

Atmel AT93C86A 3408 Revision H (January 2007)

Add "Bottom View" to page 1 Ultra Thin MiniMap package drawing page 4 revise Note 1 added "ensured by characterization".

Atmel AT93C86A 3408 Revision G (July 2006)

Revision history implemented. Delete 'Preliminary' status from data sheet; Add 'Ultra Thin' description to MLP 2x3 package; Delete '1.8V not available' on Figure 1 Note; Add 1.8V range on Table 4 under Write Cycle Time.

The Microchip Website

Microchip provides online support via our website at http://www.microchip.com/. This website is used to make files and information easily available to customers. Some of the content available includes:

- Product Support Data sheets and errata, application notes and sample programs, design resources, user's
 guides and hardware support documents, latest software releases and archived software
- General Technical Support Frequently Asked Questions (FAQs), technical support requests, online discussion groups, Microchip design partner program member listing
- Business of Microchip Product selector and ordering guides, latest Microchip press releases, listing of seminars and events, listings of Microchip sales offices, distributors and factory representatives

Product Change Notification Service

Microchip's product change notification service helps keep customers current on Microchip products. Subscribers will receive email notification whenever there are changes, updates, revisions or errata related to a specified product family or development tool of interest.

To register, go to http://www.microchip.com/pcn and follow the registration instructions.

Customer Support

Users of Microchip products can receive assistance through several channels:

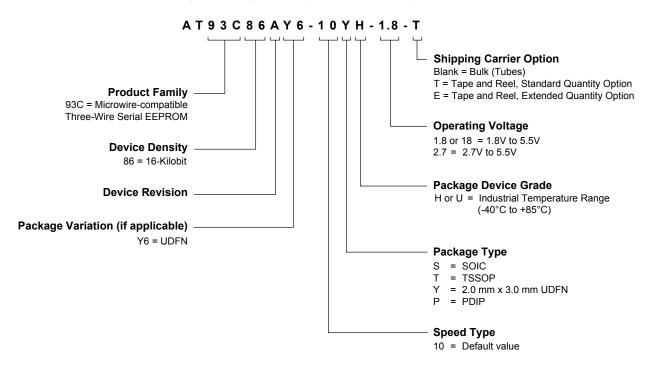
- · Distributor or Representative
- · Local Sales Office
- Embedded Solutions Engineer (ESE)
- · Technical Support

Customers should contact their distributor, representative or ESE for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in this document.

Technical support is available through the website at: http://www.microchip.com/support

Product Identification System

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.



Note: Refer to automotive data sheet for automotive grade ordering information.

Examples

Device	Package	Package Drawing Code	Package Option	Voltage Range	Shipping Carrier Option	Device Grade
AT93C86A-10SU-1.8	SOIC	SN	S	1.8V to 5.5V	Bulk (Tubes)	Industrial
AT93C86A-10SU-2.7-T	SOIC	SN	S	2.7V to 5.5V	Tape and Reel	Temperature (-40°C to 85°C)
AT93C86A-10TU-1.8	TSSOP	ST	Т	1.8V to 5.5V	Bulk (Tubes)	·
AT93C86A-10TU-2.7-T	TSSOP	ST	Т	2.7V to 5.5V	Tape and Reel	
AT93C86AY6-10YH-1.8-T	UDFN	Q4B	Y	1.8V to 5.5V	Tape and Reel	
AT93C86AY6-10YH-18-E	UDFN	Q4B	Y	1.8V to 5.5V	Extended Qty., Tape and Reel	
AT93C86A-10PU-2.7	PDIP	Р	Р	2.7V to 5.5V	Bulk (Tubes)	

Microchip Devices Code Protection Feature

Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.

DS20006261A-page 30 © 2019 Microchip Technology Inc.

- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Legal Notice

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Trademarks

The Microchip name and logo, the Microchip logo, Adaptec, AnyRate, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PackeTime, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TempTrackr, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, FlashTec, Hyper Speed Control, HyperLight Load, IntelliMOS, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet-Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, Vite, WinPath, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, BlueSky, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, EtherGREEN, In-Circuit Serial Programming, ICSP, INICnet, Inter-Chip Connectivity, JitterBlocker, KleerNet, KleerNet logo, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, SAM-ICE, Serial Quad I/O, SMART-I.S., SQI, SuperSwitcher, SuperSwitcher II, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2019, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-5224-5156-3

AMBA, Arm, Arm7, Arm7TDMI, Arm9, Arm11, Artisan, big.LITTLE, Cordio, CoreLink, CoreSight, Cortex, DesignStart, DynamIQ, Jazelle, Keil, Mali, Mbed, Mbed Enabled, NEON, POP, RealView, SecurCore, Socrates, Thumb, TrustZone, ULINK, ULINK2, ULINK-ME, ULINK-PLUS, ULINKpro, µVision, Versatile are trademarks or registered trademarks of Arm Limited (or its subsidiaries) in the US and/or elsewhere.

Quality Management System

For information regarding Microchip's Quality Management Systems, please visit http://www.microchip.com/quality.



Worldwide Sales and Service

AMERICAS	ASIA/PACIFIC	ASIA/PACIFIC	EUROPE
Corporate Office	Australia - Sydney	India - Bangalore	Austria - Wels
2355 West Chandler Blvd.	Tel: 61-2-9868-6733	Tel: 91-80-3090-4444	Tel: 43-7242-2244-39
Chandler, AZ 85224-6199	China - Beijing	India - New Delhi	Fax: 43-7242-2244-393
Tel: 480-792-7200	Tel: 86-10-8569-7000	Tel: 91-11-4160-8631	Denmark - Copenhagen
Fax: 480-792-7277	China - Chengdu	India - Pune	Tel: 45-4450-2828
Technical Support:	Tel: 86-28-8665-5511	Tel: 91-20-4121-0141	Fax: 45-4485-2829
http://www.microchip.com/support	China - Chongqing	Japan - Osaka	Finland - Espoo
Web Address:	Tel: 86-23-8980-9588	Tel: 81-6-6152-7160	Tel: 358-9-4520-820
http://www.microchip.com	China - Dongguan	Japan - Tokyo	France - Paris
Atlanta	Tel: 86-769-8702-9880	Tel: 81-3-6880- 3770	Tel: 33-1-69-53-63-20
Duluth, GA	China - Guangzhou	Korea - Daegu	Fax: 33-1-69-30-90-79
Tel: 678-957-9614	Tel: 86-20-8755-8029	Tel: 82-53-744-4301	Germany - Garching
Fax: 678-957-1455	China - Hangzhou	Korea - Seoul	Tel: 49-8931-9700
Austin, TX	Tel: 86-571-8792-8115	Tel: 82-2-554-7200	Germany - Haan
Tel: 512-257-3370	China - Hong Kong SAR	Malaysia - Kuala Lumpur	Tel: 49-2129-3766400
Boston	Tel: 852-2943-5100	Tel: 60-3-7651-7906	Germany - Heilbronn
Westborough, MA	China - Nanjing	Malaysia - Penang	Tel: 49-7131-72400
Tel: 774-760-0087	Tel: 86-25-8473-2460	Tel: 60-4-227-8870	Germany - Karlsruhe
Fax: 774-760-0088	China - Qingdao	Philippines - Manila	Tel: 49-721-625370
Chicago	Tel: 86-532-8502-7355	Tel: 63-2-634-9065	Germany - Munich
Itasca, IL	China - Shanghai	Singapore	Tel: 49-89-627-144-0
Tel: 630-285-0071	Tel: 86-21-3326-8000	Tel: 65-6334-8870	Fax: 49-89-627-144-44
Fax: 630-285-0075	China - Shenyang	Taiwan - Hsin Chu	Germany - Rosenheim
Dallas	Tel: 86-24-2334-2829	Tel: 886-3-577-8366	Tel: 49-8031-354-560
Addison, TX	China - Shenzhen	Taiwan - Kaohsiung	Israel - Ra'anana
Tel: 972-818-7423	Tel: 86-755-8864-2200	Tel: 886-7-213-7830	Tel: 972-9-744-7705
Fax: 972-818-2924	China - Suzhou	Taiwan - Taipei	Italy - Milan
Detroit	Tel: 86-186-6233-1526	Tel: 886-2-2508-8600	Tel: 39-0331-742611
Novi, MI	China - Wuhan	Thailand - Bangkok	Fax: 39-0331-466781
Tel: 248-848-4000	Tel: 86-27-5980-5300	Tel: 66-2-694-1351	Italy - Padova
Houston, TX	China - Xian	Vietnam - Ho Chi Minh	Tel: 39-049-7625286
Tel: 281-894-5983	Tel: 86-29-8833-7252	Tel: 84-28-5448-2100	Netherlands - Drunen
Indianapolis	China - Xiamen		Tel: 31-416-690399
Noblesville, IN	Tel: 86-592-2388138		Fax: 31-416-690340
Tel: 317-773-8323	China - Zhuhai		Norway - Trondheim
Fax: 317-773-5453	Tel: 86-756-3210040		Tel: 47-72884388
Tel: 317-536-2380			Poland - Warsaw
Los Angeles			Tel: 48-22-3325737
Mission Viejo, CA			Romania - Bucharest
Tel: 949-462-9523			Tel: 40-21-407-87-50
Fax: 949-462-9608			Spain - Madrid
Tel: 951-273-7800			Tel: 34-91-708-08-90
Raleigh, NC			Fax: 34-91-708-08-91
Tel: 919-844-7510			Sweden - Gothenberg
New York, NY			Tel: 46-31-704-60-40
Tel: 631-435-6000			Sweden - Stockholm
San Jose, CA			Tel: 46-8-5090-4654
Tel: 408-735-9110			UK - Wokingham
Tel: 408-436-4270			Tel: 44-118-921-5800
Canada - Toronto			Fax: 44-118-921-5820
Tel: 905-695-1980			
Fax: 905-695-2078			

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for microchip manufacturer:

Other Similar products are found below:

SW500024 ATSTK600-RC46 MA330027 AVRSB100 ATSTK600-RC14 ATF750C-10GM/883 AT28C010-20FM/883 MSLB9082DGA
PIC18C658-E/PT SY89544UMG DSC1001AI5-033.3330 DSC1123AL1-150.0000 DSC1001AI5-125.0060 MX573NBA622M080
DSC1001AI5-100.0000 DSC1001AI5-048.0000 MCP73834-CNI/MF DSC1123CI2-212.5000 DSPIC33EP128GS702-E/SO PIC16C73B20/SS DSC1001CI2-030.0000 KSZ8864RMNUB DSC1001CL5-114.0000 PIC18LF45K42-E/P ATXMEGA64A1U-C7U DSC1001DL5033.0000 AT97SC3205T-H3M4C10B DSC1001BI5-020.0000 DSC1001BL1-016.0000 DSC1001AE1-006.1440 PCM16XB1 MCP1630RDDDBK3 MCP1700T-3002E/MB MCP2030DM-TPR MCP3421DM-BFG MCP3551DM-PCTL MCP4642T-503E/MF MCP607-I/SN
MCP621-E/SN MIC1344YFT-EV MIC23451-AAAYFL-T5 MIC5209YU-TR MIC5356-JGYMME PIC10F206-E/P PIC16F677-I/P
PIC16F914-I/P PIC16LC621A-04I/SO PIC18F448-I/P PIC18F4680-E/ML PIC18LF2523-ISO